Unit: mm

TOSHIBA Transistor Silicon NPN Triple Diffused Type

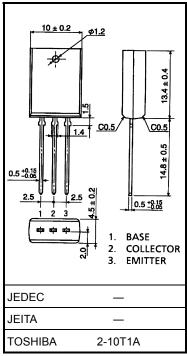
2SC5684

Switching Regulator and High-Voltage Switching Applications

- Excellent switching times (IC = 0.3 A) : $t_r = 0.7 \mu s \text{ (max)}, t_f = 0.5 \mu s \text{ (max)}$
- High collector breakdown voltage: VCEO = 800 V
- High-speed DC-DC converter applications

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	900	V	
Collector-emitter voltage		V _{CEO}	800	V	
Emitter-base voltage		V _{EBO}	7	٧	
Collector current	DC	IC	0.8	А	
	Pulse	I _{CP}	1.5		
Base current		ΙΒ	0.4	Α	
Collector power dissipation		PC	1.8	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

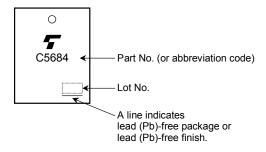


Weight: 1.5 g (typ.)

Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 720 V, I _E = 0	_	_	100	μA
Emitter cut-off current		I _{EBO}	V _{EB} = 7 V, I _C = 0	_	_	1	mA
Collector-base breakdown voltage		V (BR) CBO	I _C = 1 mA, I _E = 0	900	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	800	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA	10	_	_	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.08 A	15	_	60	
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 0.3 A, I _B = 0.06 A	_	_	1.0	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 0.3 A, I _B = 0.06 A	_	_	1.2	V
Switching time §	Rise time	t _r	20 µs Input → Output 20 µs Input → CS BB2 VCC ≈ 360 V	_	_	0.7	
	Storage time	t _{stg}		_	_	4.5	μs
	Fall time	t _f	I _{B1} = 0.06 A, I _{B2} = −0.12 A Duty cycle ≤ 1%	1	_	0.5	

Marking



2 2004-07-26

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